



Title	Quantum percolation in quantum spin Hall antidot systems
Author(s)	Chu, RL; Liu, J; Shen, SQ
Citation	EPL (Europhysics Letters), 2012, v. 100 n. 1, p. 17013:1-5
Issued Date	2012
URL	http://hdl.handle.net/10722/225568
Rights	EPL (Europhysics Letters). Copyright © Institute of Physics Publishing Ltd.; This is an author-created, un-copied version of an article published in EPL (Europhysics Letters). IOP Publishing Ltd is not responsible for any errors or omissions in this version of the manuscript or any version derived from it. The Version of Record is available online at http://dx.doi.org/10.1209/0295-5075/100/17013; This work is licensed under a Creative Commons Attribution-NonCommercial-NoDerivatives 4.0 International License.

Quantum percolation in quantum spin Hall antidot systems

Rui-Lin Chu,¹ Jie Lu,^{2,1} and Shun-Qing Shen¹

¹*Department of Physics, The University of Hong Kong, Pokfulam Road, Hong Kong*

²*College of Physics, Hebei Advanced Thin Films Laboratory, Hebei Normal University, Shijiazhuang, China*

(Dated: February 27, 2012)

We study the influences of antidot-induced bound states on transport properties of two-dimensional quantum spin Hall insulators. The bound states are found able to induce quantum percolation in the originally insulating bulk. At some critical antidot densities, the quantum spin Hall phase can be completely destroyed due to the maximum quantum percolation. For systems with periodic boundaries, the maximum quantum percolation between the bound states creates intermediate extended states in the bulk which is originally gapped and insulating. The antidot induced bound states plays the same role as the magnetic field in the quantum Hall effect, both makes electrons go into cyclotron motions. We also draw an analogy between the quantum percolation phenomena in this system and that in the network models of quantum Hall effect.

PACS numbers: 73.23.-b, 73.20.Jc, 73.43.-f

Quantum spin Hall (QSH) insulators have been known as two-dimensional (2D) topological insulators, which have been studied intensively because of the novel physics they host.¹⁻³ The bulk of these systems shows insulating gaps but the system boundaries processes time-reversal symmetry (TRS) protected gapless surface or edge modes, characterized by the Z_2 topological invariant.⁴⁻⁹ Disorders are believed not able to cause backscattering of these modes because of their spin-momentum locking. In two dimension, these gapless modes are also known as helical edge states that are responsible for the QSH effect⁴⁻⁶. In our previous works, we have shown that defects in the form of vacancies in 2D topological insulators can induce bound states that appear within the bulk band gap^{10,11}. Electrons are able to go into cyclotron motions around the vacancies through these bound states, which is caused by the non-trivial underlying topology of the system. In reality, defects inevitably exist in 2D QSH systems. It is however not particularly clear how these bound states affect the QSH phase as well as the transport properties of the helical edge states.

In this paper, we study QSH systems in which vacancies appear as arrays using theoretical models. Such kind of man-made systems have been referred to as antidot arrays.^{12,13} In the well-studied 2D electron systems such as GaAs/GaAs based and InAs based heterojunctions, antidot arrays display intriguing physical properties.¹⁴ QSH insulators are ideal platforms for studying antidot systems since they are true 2D materials with exotic physical properties. By defining antidot lattices on the 2D QSH systems, we show that antidots induce extra energy bands which can greatly smear the band gap. When exceeding the critical antidot density, the QSH phase can be completely destroyed. When antidots are randomly distributed, the existence of antidot-induced energy bands and band gap smearing is confirmed by calculating the density of states of the 2D system. We also study the transport properties in these systems under different boundary conditions. It is found that quantum percolation occurs taking the bound states as step-

ping stones. Physically this happens because of the finite spatial distribution and overlapping of these bound states. In the open boundary condition (OBC), the bound states formed transverse percolation channels allow the backscattering between conducting channels at opposite edges of the sample with the same spin, which then destroys the QSH phase (see Fig. 1e). In the closed boundary condition (CBC), the longitudinal percolation forms new conducting channels between the source and drain in a two-terminal configuration, as illustrated in Fig. 1d, which can be viewed as truly extended states. We found that transition from QSH phase to conventional insulating phase accompanies appearance of these extended states.

Following our previous works^{10,11}, a modified Dirac model is used to describe the 2D QSH insulators¹⁵,

$$H_0 = v\mathbf{p} \cdot \boldsymbol{\alpha} + (mv^2 - Bp^2)\beta, \quad (1)$$

where $-Bp^2 = -B(p_x^2 + p_y^2)$ is the quadratic correction to the topological mass term mv^2 , $p_i = -i\hbar\partial_i$ ($i \in \{x, y\}$) is the momentum operator. v , m and B have the dimension of speed, mass and reciprocal mass, respectively. The Dirac matrices satisfy the anti-commutation relations $\alpha_i\alpha_j = -\alpha_j\alpha_i$ ($i \neq j$), $\alpha_i\beta = -\beta\alpha_i$ and $\alpha_i^2 = \beta^2 = 1$. A common representation of the Dirac matrices can be expressed as,

$$\alpha_i = \sigma_x \otimes \sigma_i, \quad \beta = \sigma_z \otimes \sigma_0, \quad (2)$$

where $\sigma_{i=x,y,z}$ are the Pauli matrices, σ_0 is the 2×2 unit matrix, and \otimes represents the Kronecker product. The Hamiltonian (1) preserves time-reversal symmetry $\mathcal{T}H_0\mathcal{T}^{-1} = H_0$, where $\mathcal{T} = -i\alpha_x\alpha_z\hat{K}$ is the time-reversal operator and \hat{K} is the complex conjugate operator. The topological nature of this Hamiltonian has been discussed in detail in our previous works¹⁵. This system is topologically non-trivial (with $Z_2 = 1$) while $mB > 0$, and trivial (with $Z_2 = 0$) while $mB < 0$.⁴

After appropriately reordering the basis, the Hamilto-

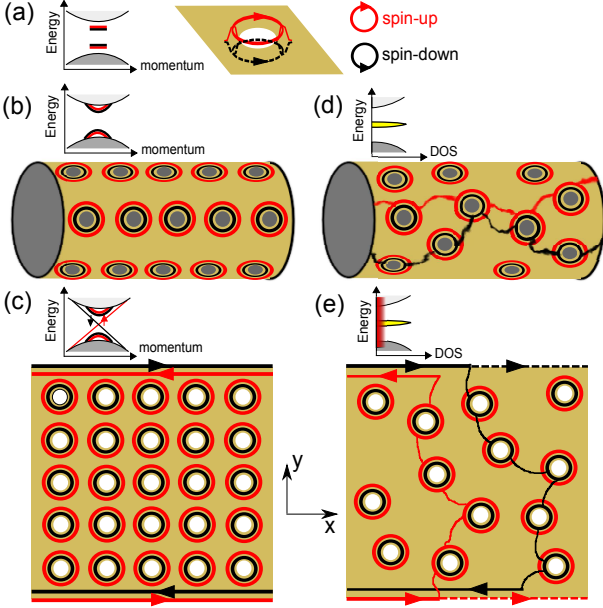


FIG. 1: (Color online) Schematic description of the influences of in-gap bound states in 2D TIs. (a) Bound states induced by a single antidot. Red (black) colors represent the spin-up (-down) component; (b) Antidot lattice with CBC that is infinite in x -direction. Additional antidot induced energy bands appears in the bulk band gap; (c) Antidot lattice with OBC, the antidot bands co-exist with the helical edge states; (d) In CBC, at a critical antidot density, the electron percolates through the overlapping bound states and form longitudinal conducting channels; (e) In OBC, transverse percolation channels allows backscattering between edge states on the opposite edges and finally destroy the QSH phase.

nian (1) can be decoupled into two blocks^{10,11},

$$h_{\pm} = (mv^2 - Bp^2)\sigma_z + v(p_x\sigma_x \pm p_y\sigma_y), \quad (3)$$

with h_- being the time-reversal counterpart of h_+ . Because the system keeps TRS, we only consider the h_+ block. When being discretized onto an square-lattice, the tight-binding version of h_+ reads,

$$h_+^{\text{TB}} = \sum_{\mathbf{i}} C_{\mathbf{i}\uparrow}^\dagger \mathbf{M} C_{\mathbf{i}\uparrow} + \sum_{\mathbf{i}} \left(C_{\mathbf{i}+\delta_{\mathbf{x},\uparrow}}^\dagger \mathbf{t}_{\mathbf{x}} C_{\mathbf{i}\uparrow} + \text{H.c.} \right) + \sum_{\mathbf{i}} \left(C_{\mathbf{i}+\delta_{\mathbf{y},\uparrow}}^\dagger \mathbf{t}_{\mathbf{y}} C_{\mathbf{i}\uparrow} + \text{H.c.} \right) \quad (4)$$

where $C_{\mathbf{i}\uparrow} = (c_{\mathbf{i}\uparrow}, d_{\mathbf{i}\uparrow})^T$ is the annihilation operator of electrons at site \mathbf{i} with up spins but belonging to two different bands⁶, $\delta_{\mathbf{x}}$ ($\delta_{\mathbf{y}}$) is the unit vector displacement (with length a) between two nearest-neighbor sites in the x (y) direction, and the on-site energy and hopping matrices in x (y) directions reads,

$$\mathbf{M} = \left(mv^2 - \frac{4B\hbar^2}{a^2} \right) \sigma_z, \quad \mathbf{t}_{\mathbf{x}(y)} = -\frac{i\hbar v}{2a} \sigma_{x(y)} + \frac{B\hbar^2}{a^2} \sigma_z. \quad (5)$$

Numerically, the antidot is modeled by leaving the antidot regions as vacancies on the tight binding lattice. The CBC geometry is realized by adopting periodic boundary condition in the y direction (see Fig. 1). Transport features are investigated through the combination of the non-equilibrium Green's function¹⁷ and the Landauer-Büttiker¹⁸ formalism. During the calculation, the effects of each semi-infinite leads are taken into account by introducing the corresponding self-energy terms. To clearly illustrate the physics, we adopt such model parameters to describe the clean substrate: $mv^2 = -10$, $\hbar v = 72$, and $B\hbar^2 = -28$, which is in the topologically non-trivial regime, i.e., $mB > 0$. In the tight binding calculations, the lattice constant is set to be $a = 1$.

For antidots on a finite size sample, its induced bound state can be identified by directly diagonalizing the total tight-binding Hamiltonian. The bound states are states that have spatially localized wave functions and discrete energy spectrum. The antidot-induced bound states in 2D topological insulators are found both in the bulk band and in the band gap with wave function confined around it (Fig. 2a)^{10,11}. However, those with energies existing in the bulk band gap are of most interest to us since they coexist with helical edge states in the QSH insulator. As an illustration, we plot out the in-gap bound state wave function for a single antidot and a simple antidot array in Fig. 2. As is shown, the bound states are indeed localized around the antidots. Away from the center their wave functions quickly decay, which can be approximated in the form $\psi e^{-r/\xi}$.^{10,11,15} The characteristic decay length ξ in Fig. 2 in theory is about $11a$, which agrees well with our numerical results. For the antidot arrays, as is seen in Fig. 2, the in-gap bound states they induce overlap with each other and eventually become connected.

Consider an antidot array with 100-sites in width. The finite-size effect-induced energy gap in the clean system of this size is around 1.6×10^{-3} ,¹⁶ which is negligible compared with the bulk gap ($2mv^2 = 20$). The antidots are equally spaced in both x and y directions with the spacing being D sites. We calculate the spectrum of the antidot lattice with $D = 5, 4, 3, 2$ under both open and closed boundary conditions. Meanwhile the wave function of the lowest conduction band at $k_x^0 = \pi/(D+1)$ (red solid circles in Fig. 3) is taken as an example to demonstrate the emergence of the intermediate states formed by the bound states in the band gap (Fig. 3 insets).

As the antidots become dense, the bulk band gap is found to close up and then re-opens, as is shown in Fig. 3. When $D = 5$ and 4, the edge states survive under OBC. Meanwhile the antidot-induced energy bands already appear between $E = \pm 10$ where the bulk band gap was, as is seen in the lowest conduction band wave functions in CBC in the inset of Fig. 3e. When D gradually decreases, the band gap shrinks more. At $D = 3$ the edge states in OBC disappear and the band gap is no longer non-trivial (Fig. 3c). In this case, the lowest conduction band becomes a bulk mode, as shown in the inset of Fig. 3(c). Since the antidot size cannot be con-

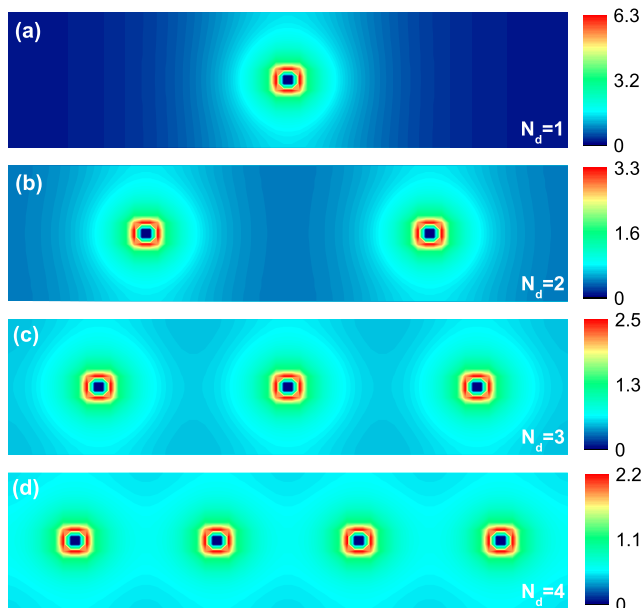


FIG. 2: (Color online) Connecting of in-gap bound states as the antidots become dense. 2×2 sized antidots are equally spaced on a 20×72 torus geometry. (a)-(d) show the evolution of overlapping for in-gap bound state wave functions with antidot number $N_d = 1$ to 4.

tinuously changed on the lattice model, this implies that there exists a critical point between $D = 4$ and $D = 3$ where the band gap vanishes and the QSH phase is destroyed. As the antidots become denser, the band gap further opens up and no states can be found in the low energy regime.

After consider the physical picture illustrated in Fig.2, it can be inferred that there is a critical point where the maximum percolation caused by the antidot-induced bound states exists. This can be explicitly demonstrated by calculating the two-terminal transmission coefficient T_{lr} with antidots randomly distributed in the sample. We choose a 2D sample composed by $W \times L = 160 \times 160$ sites. 1×1 sized antidots are randomly patterned at a density p , which is defined as the number of antidot sites divided by WL . For example, in the antidot array case of Fig.3c and Fig.3g, the antidot density is $p = 1/16$. The Fermi level is fixed at $E_F^0 \approx 0$ but carefully avoided from the tiny gap from finite-size effect. The T_{lr} versus p curves under OBC and CBC are shown in Fig. 4(a) and (b), respectively. For each p , the sample averaging is taken with 100 random antidot configurations. Indeed, when p is small, T_{lr} remains one/zero under open/closed boundary condition. But when p approaches a critical value $p_c \approx 9/160$, under OBC T_{lr} drops dramatically while under CBC T_{lr} acquires a sharp peak with the peak value approaching 1, which is a signature of maximum percolation in the bulk. When $p \gg p_c$, T_{lr} vanishes under both boundary conditions. The critical point value we find $p_c = 9/160$ agrees very well with that we inferred from the previous results from the antidot arrays in Fig.3.

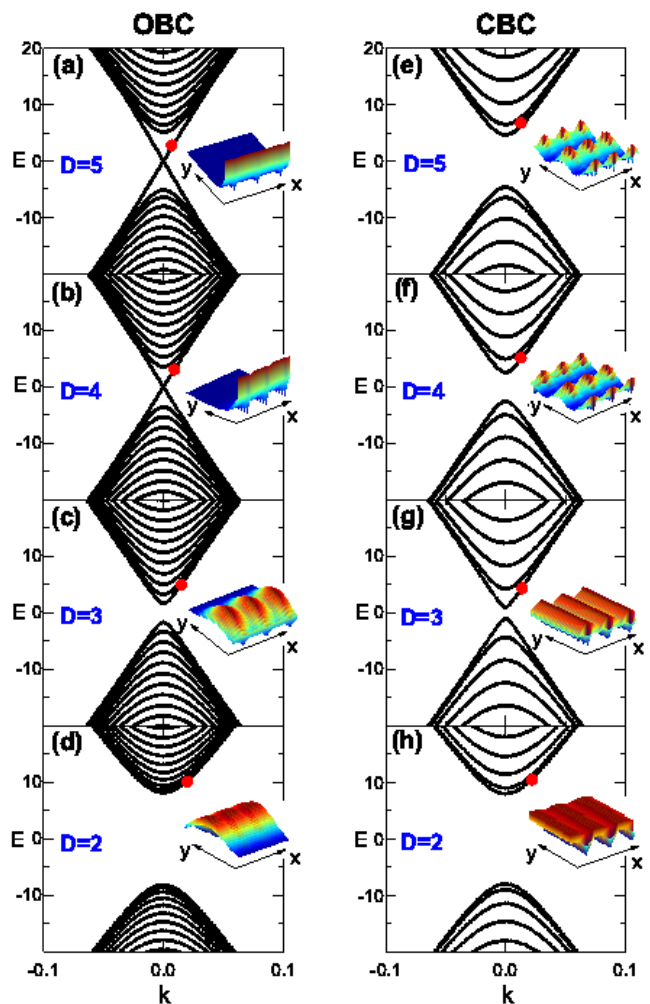


FIG. 3: (Color online) Energy spectrum of QSH antidot lattices at different antidot spacing D under OBC and CBC. The width is 100-sites and the antidot size is 1×1 site. (a)-(d) are for OBC, (e)-(h) are for CBC. The solid red circle in each figure indicate $k_x^0 = 0.1 \frac{\pi}{(D+1)}$ on the lowest conduction band, the corresponding wave function for three principal layers are shown in the insets.

And thus the physical picture of bound state induced percolation can be confirmed.

The above picture is further confirmed by calculating the system's density of states. To eliminate the contribution of the edge states in the bulk band gap, CBC in both x and y directions are adopted. We choose three typical antidot densities: $p_1 = 5/160$, $p_c = 9/160$ and $p_2 = 15/160$. For each density, the averaged density of states is calculated with 100 random antidot configurations using the kernel polynomial method²². When $p < p_c$, the original inverted bulk gap is reduced but still survives to protect the QSH phase, as is shown in Fig. 4(c). For $p = p_c$, a sharp peak appears at $E = 0$ as is shown in Fig. 4(d), which is from the conducting channel in the bulk formed by the in-gap bound state. The gap seen between the conduction and valence band in Fig.

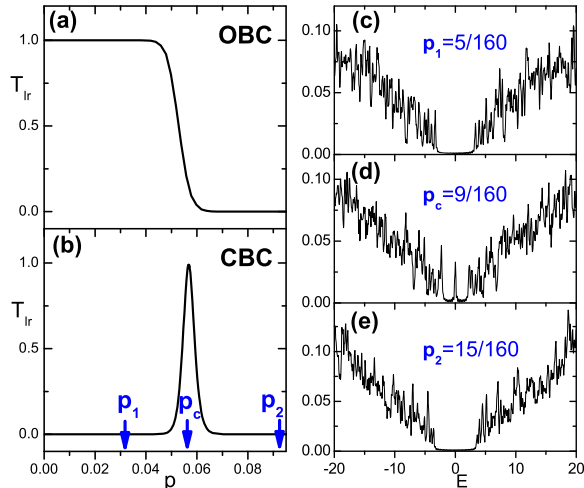


FIG. 4: (Color online) Quantum percolation of electron through in-gap bound states induced by randomly distributed antidots. (a) and (b) show the two terminal transmission coefficient T_{lr} v.s. p curves under OBC and CBC with sample averaging. The sample is $W \times L = 160 \times 160$ in size. (c)-(e) are the corresponding density of states at $p_1 = \frac{5}{160}$, $p_c = \frac{9}{160}$ and $p_2 = \frac{15}{160}$, respectively. In these calculations, only the h_+ sub-block is considered. When the time-reversal symmetry is conserved, the h_- block produces the same result.

4(d) is solely due to the finite size effect, because it can be inferred from Fig. 3(g) that in the continuum limit both the valence and conduction band spectrum should become continuous. When $p > p_c$, the band gap re-opens and the system becomes a conventional insulator [Fig. 4(e)].

It is well established in the quantum Hall effect that the quantum percolation process is responsible for the transition between the quantized Hall conductance plateaus^{19,20}, which is a direct manifestation of the localization-delocalization quantum phase transition. In the quantum Hall effect, electrons go into cyclotron motions because of the high perpendicular magnetic field in which process the disorders help to pin the cyclotron orbitals locally. The quantum percolation can thus be intuitively understood in the sense that the cyclotron orbitals

connect with each other at some critical external conditions (e.g.: magnetic field strength, Fermi surface, etc). Based on this physical picture, the Chalker-Coddington network(CCN) model is developed which gracefully describes the localization-delocalization transition in the quantum Hall effect in the presence of disorders^{19,21}. Upon each of such transition, it is also accompanied by the change of the topological order of the system, namely the Thouless-Kohmoto-Nightingale-Nijs integer²³, which changes by 1 at each of these transitions.

In the QSH insulator we studied, the maximum percolation accompanied with destroying of the QSH phase can also be seen as such kind of localization-delocalization quantum phase transition. But in this case, it is accompanied by the change in the Z_2 topological invariant from 1 to 0.^{24,25} Through our previous papers, it is made clear that the bound states themselves have helical nature (or chiral when considering only h_+ or h_- sub-block)^{10,11}, which is similar to the chiral nature of cyclotron orbitals in the quantum Hall effect. By analogy it is possible that at the critical antidot density, the bound states connect and form 2D networks in real space, i.e. the formation of percolation. At this condition, truly extended states exist and the localization length of electrons should diverge. The percolation provides new conducting channels in the bulk, which allows edge states be scattered backward across the sample through the other edge in OBC [as is seen in the drop of T_{lr} in Fig. 4(a)]. Meanwhile, the existence of extended states is proven by the dramatic raise of T_{lr} shown in Fig. 4(b). It is noted that in the QSH insulator, there are always two copies of percolation channels with opposite chirality, one from h_+ and the other from h_- .

To conclude, our results indicate that appropriate density of antidots in a 2D QSH insulators can dramatically change the sample's electronic structure and consequently the transport features. There exists a critical antidot density at which the bulk electrons becomes truly delocalized because of the quantum percolation channels across the sample formed by the antidot induced bound states. This localization-delocalization transition is accompanied by the vanishing of the QSH phase.

This work was supported by the Research Grant Council of Hong Kong under Grant No. HKU7051/11P, and by National Natural Science Foundation of China (Grant No. 11104060).

¹ M. Z. Hasan and C. L. Kane, Rev. Mod. Phys. 82, 3045 (2010).

² Xiao-Liang Qi and Shou-Cheng Zhang, Rev. Mod. Phys. 83, 1057 (2011).

³ M. Z. Hasan and J. E. Moore, Annu. Rev. Condens. Matter Phys. 2, 55 (2011).

⁴ C. L. Kane and E. J. Mele, Phys. Rev. Lett. 95, 146802 (2005).

⁵ C. L. Kane and E. J. Mele, Phys. Rev. Lett. 95, 226801

(2005).

⁶ B. A. Bernevig, T. L. Hughes, and S. C. Zhang, Science 314, 1757 (2006).

⁷ M. König, S. Wiedmann, C. Brune, A. Roth, H. Buhmann, L. W. Molenkamp, X. L. Qi, and S. C. Zhang, Science 318, 766 (2007).

⁸ M. König, H. Buhmann, L. W. Molenkamp, T. Hughes, C. X. Liu, X. L. Qi, and S. C. Zhang, J. Phys. Soc. Jpn. 77, 031007 (2008).

- ⁹ A. Roth, C. Brune, H. Buhmann, L. W. Molenkamp, J. Maciejko, X. L. Qi, and S. C. Zhang, *Science* **325**, 294 (2009).
- ¹⁰ W. Y. Shan, J. Lu, H. Z. Lu, and S. Q. Shen, *Phys. Rev. B* **84**, 035307 (2011).
- ¹¹ J. Lu, W. Y. Shan, H. Z. Lu, and S. Q. Shen, *New J. Phys.* **13**, 103016 (2011).
- ¹² R. Fleischmann, T. Geisel, and R. Ketzmerick, *Phys. Rev. Lett.* **68**, 1367 (1992).
- ¹³ D. Weiss, K. Richter, A. Menschig, R. Bergmann, H. Schweizer, K. von Klitzing, and G. Weimann, *Phys. Rev. Lett.* **70**, 4118(1993).
- ¹⁴ Jonathan P. Bird, *Electron Transport in Quantum Dots*. Kluwer Academic Publishers (2003).
- ¹⁵ S. Q. Shen, W. Y. Shan, and H. Z. Lu, *Spin* **1**, 33 (2011).
- ¹⁶ B. Zhou, H. Z. Lu, R. L. Chu, S. Q. Shen, and Q. Niu, *Phys. Rev. Lett.* **101**, 246807 (2008).
- ¹⁷ S. Datta, *Electronic Transport in Mesoscopic Systems* (Cambridge University Press, 1995).
- ¹⁸ M. Büttiker, *Phys. Rev. Lett.* **57**, 1761 (1986).
- ¹⁹ B. Kramer, T. Ohtsuki, and S. Kettenmann, *Physics Report* **417**, 211 (2005).
- ²⁰ G. Xiong, S. D. Wang, Q. Niu, D. C. Tian, and X. R. Wang, *Phys. Rev. Lett.* **87**, 216802 (2001).
- ²¹ J. T. Chalker and P. D. Coddington, *J. Phys. C* **21**, 2665 (1988).
- ²² A. Weiße, G. Wellein, A. Alvermann, and H. Fehske, *Rev. Mod. Phys.* **78**, 275 (2006).
- ²³ D. J. Thouless, M. Kohmoto, M. P. Nightingale, M. Nijs, *Phys. Rev. Lett.* **49**, 405 (1982).
- ²⁴ Masaru Onoda, Yshai Avishai, and Naoto Nagaosa, *Phys. Rev. Lett.* **98**, 076802 (2007).
- ²⁵ Jian Li, Rui-Lin Chu, J. K. Jain, and Shun-Qing Shen, *Phys. Rev. Lett.* **102**, 136806 (2009).